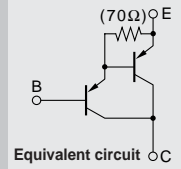


Darlington

2SB1560



Silicon PNP Epitaxial Planar Transistor (Complement to type 2SD2390)

Application : Audio, Series Regulator and General Purpose

■Absolute maximum ratings (Ta=25°C)

Symbol	Ratings	Unit
V _{CB0}	-160	V
V _{CEO}	-150	V
V _{EBO}	-5	V
I _c	-10	A
I _B	-1	A
P _c	100(T _c =25°C)	W
T _J	150	°C
T _{stg}	-55 to +150	°C

■Electrical Characteristics (Ta=25°C)

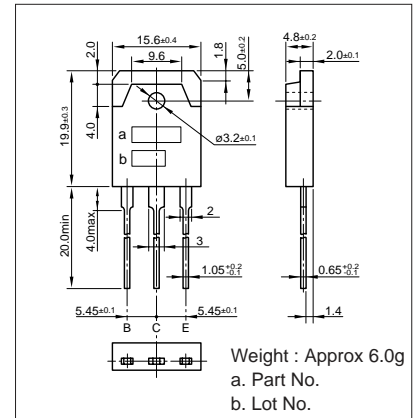
Symbol	Conditions	Ratings	Unit
I _{CB0}	V _{CB} =-160V	-100max	μA
I _{EBO}	V _{EB} =-5V	-100max	μA
V _{(BR)CEO}	I _c =-30mA	-150min	V
h _{FE}	V _{CE} =-4V, I _c =-7A	5000min*	
V _{CE(sat)}	I _c =-7A, I _B =-7mA	-2.5max	V
V _{BE(sat)}	I _c =-7A, I _B =-7mA	-3.0max	V
f _r	V _{CE} =-12V, I _E =2A	50typ	MHz
C _{OB}	V _{CB} =-10V, f=1MHz	230typ	pF

*h_{FE} Rank O(5000 to 12000), P(6500 to 20000), Y(15000 to 30000)

■Typical Switching Characteristics (Common Emitter)

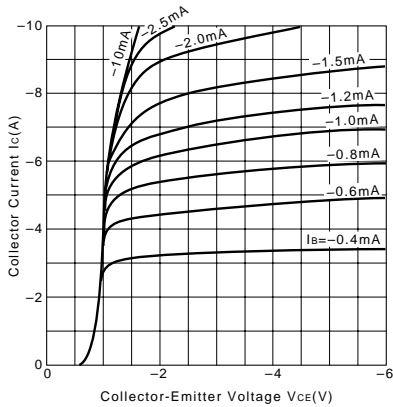
V _{CC} (V)	R _L (Ω)	I _c (A)	V _{BB1} (V)	V _{BB2} (V)	I _{B1} (mA)	I _{B2} (mA)	t _{on} (μs)	t _{stg} (μs)	t _f (μs)
-70	10	-7	-10	5	-7	7	0.8typ	3.0typ	1.2typ

External Dimensions MT-100(TO3P)

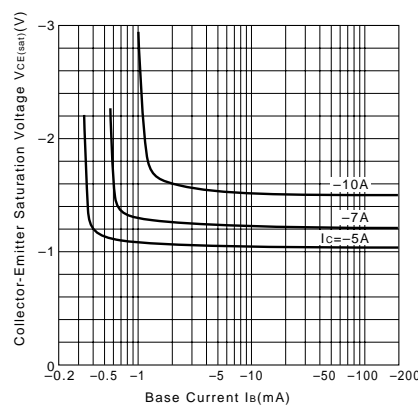


Weight : Approx 6.0g
a. Part No.
b. Lot No.

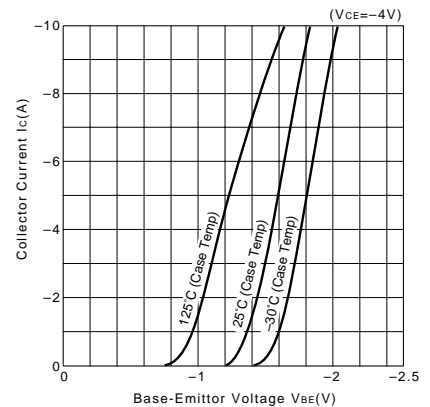
I_c-V_{CE} Characteristics (Typical)



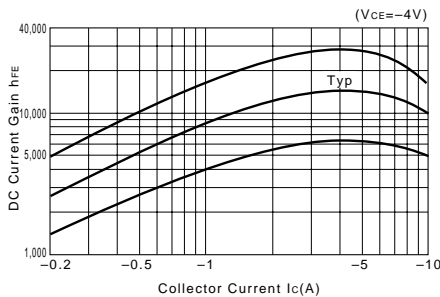
V_{CE(sat)}-I_B Characteristics (Typical)



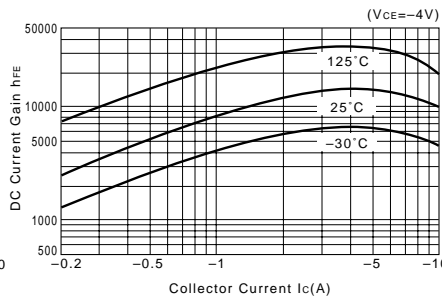
I_c-V_{BE} Temperature Characteristics (Typical)



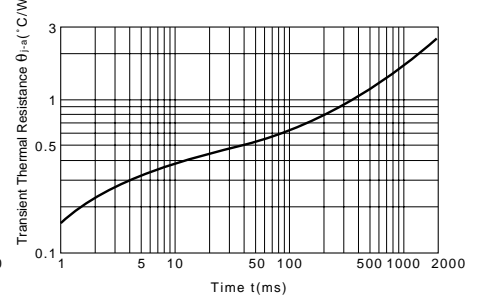
h_{FE}-I_c Characteristics (Typical)



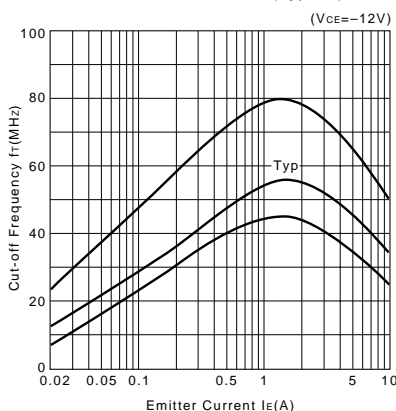
h_{FE}-I_c Temperature Characteristics (Typical)



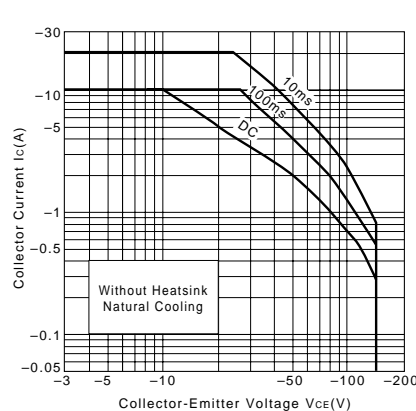
θ_{j-a}-t Characteristics



f_T-I_E Characteristics (Typical)



Safe Operating Area (Single Pulse)



P_c-T_a Derating

